## NSN 5961-01-262-5990

Transistor - Page 1 of 1



View Online at https://aerobasegroup.com/nsn/5961-01-262-5990 **Inclosure Material:** Metal **Overall Length:** 1.573 inches **Overall Height:** 0.360 inches **Overall Width:** 1.050 inches **Mounting Facility Quantity: Internal Configuration:** Field effect Joint Electronic Device Engineering Council/jedec/case Outline Designation: To-204aa **Mounting Method:** Unthreaded hole **Features Provided:** Hermetically sealed case **Semiconductor Material:** Silicon Voltage Rating In Volts Per Characteristic: 200.0 drain to gate voltage and 200.0 drain to source voltage **Current Rating Per Characteristic:** 9.00 amperes drain current **Power Rating Per Characteristic:** 75.0 watts total power dissipation **Maximum Operating Tempurature Per Measurement Point:** 150.0 degrees celsius ambient air **Test Data Document:** 81349-mil-s-19500 specification (includes engineering type bulletins, brochures, etc., that reflect specification type data in specification format; excludes commercial catalogs, industry directories, and similar trade publications, reflecting general type data on certain environmental and performance requirements and test conditions that are shown as "typical", "average", "", etc.). **Terminal Type And Quantity:** 2 pin and 1 case **Specification Data:** 81349-mil-s-19500/542 government specification Shelf Life: N/a **Unit Of Measure:** 

No Fiig: A110a0

**Demilitarization:**